NSN 5961-01-055-5930

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-055-5930 **Inclosure Material:** Plastic **Overall Length:** 0.206 inches **Overall Height:** 0.058 inches **Overall Width:** 0.320 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 70.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 225.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 135.0 degrees celsius junction **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No